

# DS2103SY/DS2103SV

# **Rectifier Diode**

Replaces December 2001 version, DS4172-5.1

DS4172-6.0 February 2003

### **FEATURES**

- Double Side Cooling
- High Surge Capability

### **APPLICATIONS**

- Rectification
- Freewheel Diode
- DC Motor Control
- Power Supplies
- Welding
- Battery Chargers

### **VOLTAGE RATINGS**

Type Number	Repetitive Peak Reverse Voltage V <sub>RRM</sub> V	Conditions
DS2103SY26	2600	$V_{RSM} = V_{RBM} + 100V$
DS2103SY25	2500	now nnw
DS2103SY24	2400	
DS2103SY23	2300	
DS2103SY22	2200	
DS2103SY21	2100	

Lower voltage grades available.

### **ORDERING INFORMATION**

When ordering, select the required part number shown in the Voltage Ratings selection table, e.g.:

DS2103SY22 for a 2200V device in a Y outline

or

DS2103SV22 for a 2200V device in a V outline

Note: Please use the complete part number when ordering and quote this number in any future correspondance relating to your order.

#### **KEY PARAMETERS**

 $V_{RRM}$  2600V  $I_{F(AV)}$  5788A  $I_{FSM}$  81000A

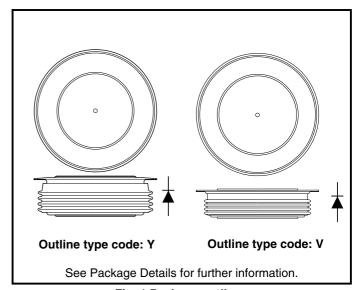


Fig. 1 Package outlines



## **CURRENT RATINGS**

# $T_{case} = 75^{\circ}C$ unless otherwise stated

Symbol	Parameter	Conditions	Max.	Units			
Double Sid	Double Side Cooled						
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load	5788	Α			
I <sub>F(RMS)</sub>	RMS value	-	9076	Α			
I <sub>F</sub>	Continuous (direct) forward current	-	8278	Α			
Single Side Cooled (Anode side)							
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load	3751	Α			
I <sub>F(RMS)</sub>	RMS value	-	5892	Α			
I <sub>F</sub>	Continuous (direct) forward current	-	4955	Α			

# $T_{\text{case}} = 100^{\circ}\text{C}$ unless otherwise stated

Symbol	Parameter	Conditions	Max.	Units			
Double Sic	Double Side Cooled						
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load	4785	Α			
I <sub>F(RMS)</sub>	RMS value	-	7516	Α			
I <sub>F</sub>	Continuous (direct) forward current	-	6725	Α			
Single Side Cooled (Anode side)							
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load	3060	Α			
I <sub>F(RMS)</sub>	RMS value	-	4807	Α			
I <sub>F</sub>	Continuous (direct) forward current	-	3950	Α			



## **SURGE RATINGS**

Symbol	Parameter	Conditions	Max.	Units
I <sub>FSM</sub>	Surge (non-repetitive) forward current	10ms half sine; T <sub>case</sub> = 175°C	65.0	kA
l²t	I <sup>2</sup> t for fusing	V <sub>R</sub> = 50% V <sub>RRM</sub> - 1/4 sine	21.1 x 10 <sup>6</sup>	A²s
I <sub>FSM</sub>	Surge (non-repetitive) forward current	10ms half sine; T <sub>case</sub> =175°C	81.0	kA
l²t	I <sup>2</sup> t for fusing	V <sub>R</sub> = 0	33 x 10 <sup>6</sup>	A²s

# THERMAL AND MECHANICAL DATA

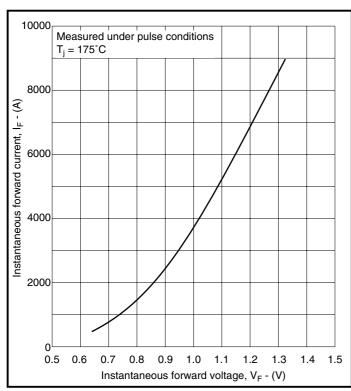
Symbol	Parameter	Conditions		Min.	Max.	Units
R <sub>th(j-c)</sub>	Thermal resistance - junction to case	Double side cooled	dc	-	0.0095	°C/W
		Circula aida aaalad	Anode dc	-	0.019	°C/W
		Single side cooled	Cathode dc	-	0.019	°C/W
R <sub>th(c-h)</sub>	Thermal resistance - case to heatsink	Clamping force 43.0kN	Double side	-	0.002	°C/W
		with mounting compound	Single side	-	0.004	°C/W
T <sub>vj</sub>	Virtual junction temperature	Forward (conducting)		-	200	°C
		Reverse (blocking)		-	175	°C
T <sub>stg</sub>	Storage temperature range			-55	175	°C
-	Clamping force			38.0	47.0	kN

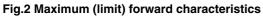


### **CHARACTERISTICS**

Symbol	Parameter	Conditions	Min.	Max.	Units
V <sub>FM</sub>	Forward voltage	At 3000A peak, T <sub>case</sub> = 25°C	-	1.05	V
I <sub>RM</sub>	Peak reverse current	At V <sub>RRM</sub> , T <sub>case</sub> = 175°C	-	150	mA
$Q_s$	Total stored charge	$I_F = 2000A$ , $dI_{RR}/dt = 3A/\mu s$ $T_{case} = 175^{\circ}C$ , $V_R = 100V$	-	3000	μС
I <sub>rr</sub>	Peak reverse recovery current		-	125	Α
V <sub>TO</sub>	Threshold voltage	At T <sub>vj</sub> = 175°C	-	0.75	٧
r <sub>T</sub>	Slope resistance	At T <sub>vj</sub> = 175°C	-	0.063	mΩ

### **CURVES**





 $V_{\rm FM}$  Equation:-

$$V_{FM} = A + Bln (I_F) + C.I_F + D.\sqrt{I_F}$$

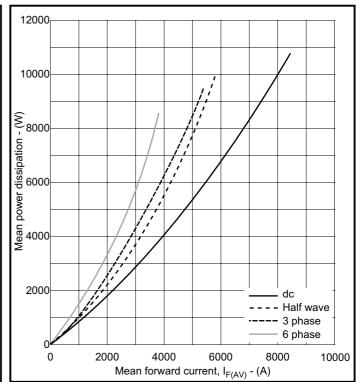


Fig.3 Dissipation curves

Where A = -0.51826

B = 0.195881  $C = 6.39 \times 10^{-5}$ 

D = -0.00544

these values are valid for  $T_j = 175^{\circ}C$  for  $I_F 500A$  to 9000A



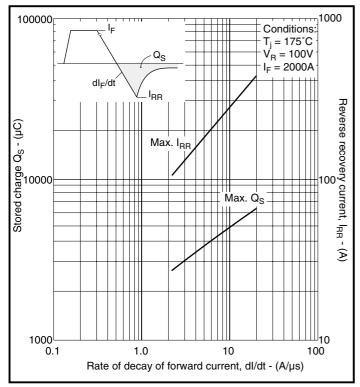


Fig.4 Total stored charge and maximum reverse recovery current

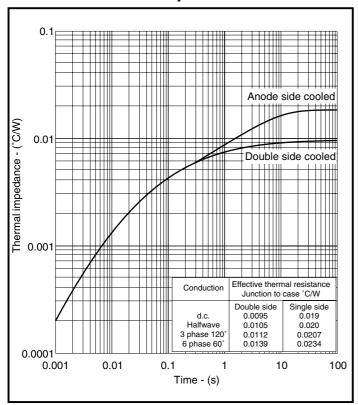


Fig.6 Maximum (limit) transient thermal impedance - junction to case

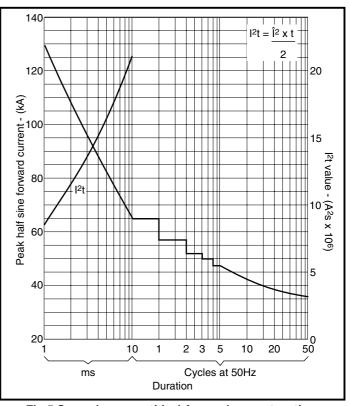
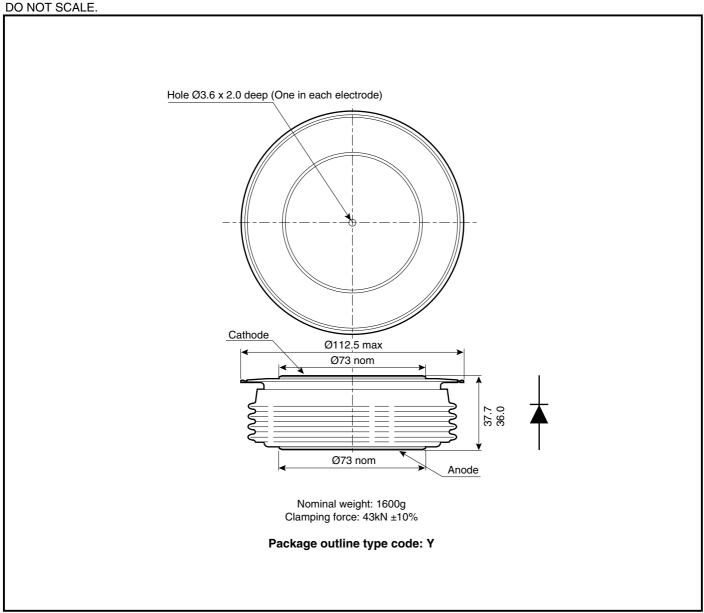


Fig.5 Surge (non-repetitive) forward current vs time (with 50%  $\rm V_{RRM}$  at  $\rm T_{case}$  175°C)



### **PACKAGE DETAILS**

For further package information, please visit our website or contact Customer Services. All dimensions in mm, unless stated otherwise.



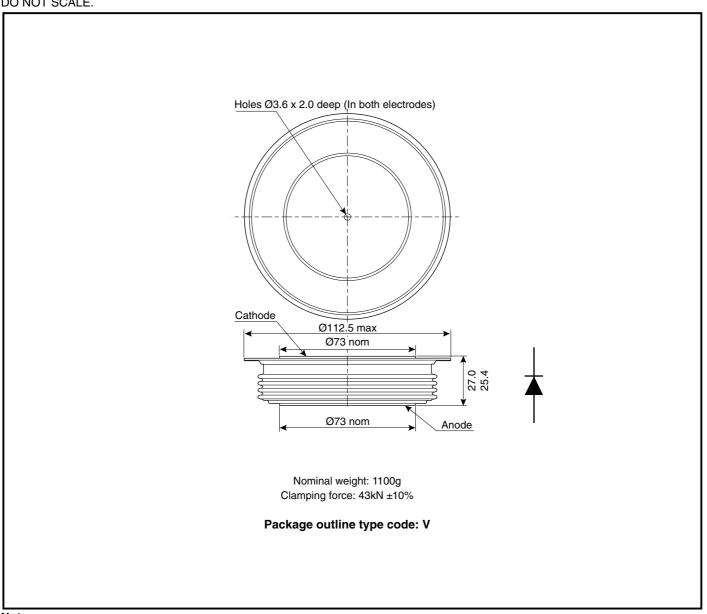
### Note:

Some packages may be supplied with gate pins and/or tags.



## **PACKAGE DETAILS**

For further package information, please visit our website or contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



### Note:

Some packages may be supplied with gate pins and/or tags.



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The Power Assembly group was set up to provide a support service for those customers requiring more than the basic semiconductor, and has developed a flexible range of heatsink and clamping systems in line with advances in device voltages and current capability of our semiconductors.

We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group offers high quality engineering support dedicated to designing new units to satisfy the growing needs of our customers.

Using the latest CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete Solution (PACs).

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The Power Assembly group has its own proprietary range of extruded aluminium heatsinks which have been designed to optimise the performance of Dynex semiconductors. Data with respect to air natural, forced air and liquid cooling (with flow rates) is available on request.

For further information on device clamps, heatsinks and assemblies, please contact your nearest sales representative or Customer Services.



http://www.dynexsemi.com

e-mail: power\_solutions@dynexsemi.com

HEADQUARTERS OPERATIONS DYNEX SEMICONDUCTOR LTD

Doddington Road, Lincoln. Lincolnshire. LN6 3LF. United Kingdom.

Tel: +44-(0)1522-500500 Fax: +44-(0)1522-500550 CUSTOMER SERVICE

Tel: +44 (0)1522 502753 / 502901. Fax: +44 (0)1522 500020

SALES OFFICES

Benelux, Italy & Switzerland: Tel: +33 (0)1 64 66 42 17. Fax: +33 (0)1 64 66 42 19.

France: Tel: +33 (0)2 47 55 75 52. Fax: +33 (0)2 47 55 75 59.

Germany, Northern Europe, Spain & Rest Of World: Tel: +44 (0)1522 502753 / 502901.

Fax: +44 (0)1522 500020

North America: Tel: (440) 259-2060. Fax: (440) 259-2059. Tel: (949) 733-3005. Fax: (949) 733-2986.

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